

Z86C02/E02/L02

LOW-COST, 512-BYTE ROM MICROCONTROLLERS

FEATURES

Device	ROM (KB)	RAM* (Bytes)	Speed (MHz)	Auto Latch	Permanent WDT
Z86C02	512	61	8	Optional	Optional
Z86E02	512	61	8	Optional	Optional
Z86L02	512	61	8	Optional	Optional

Note: *General-Purpose

- 18-Pin DIP and SOIC Packages
- 0°C to 70°C Standard Temperature

 40°C to 105°C Extended Temperature

 (Z86C02/E02 only)
- 3.0V to 5.5V Operating Range (Z86C02)4.5V to 5.5V Operating Range (Z86E02)2.0V to 3.9V Operating Range (Z86L02)
- 14 Input / Output Lines
- Five Vectored, Prioritized Interrupts from Five Different Sources
- Two On-Board Comparators
- Software Enabled Watch-Dog Timer (WDT)
- Programmable Interrupt Polarity
- Two Standby Modes: STOP and HALT
- Low-Voltage Protection

- ROM Mask/OTP Options:
 - Low-Noise (Z86C02/E02 only)
 - ROM Protect
 - Auto Latch
 - Permanent Watch-Dog Timer (WDT)
 - RC Oscillator (Z86C02/L02 Only)
 - 32 KHz Operation (Z86C02/L02 Only)
- One Programmable 8-Bit Counter/Timer with a 6-Bit Programmable Prescaler
- Power-On Reset (POR) Timer
- On-Chip Oscillator that Accepts RC, Crystal, Ceramic Resonator, LC, or External Clock Drive (C02/L02 only)
- On-Chip Oscillator that Accepts RC or External Clock Drive (Z86E02 SL1903 only)
- On-Chip Oscillator that Accepts Crystal, Ceramic Resonator, LC, or External Clock Drive (Z86E02 only)
- Clock-Free WDT Reset
- Low-Power Consumption (50mw)
- Fast Instruction Pointer (1.5µs @ 8 MHz)
- Fourteen Digital Inputs at CMOS Levels; Schmitt-Triggered

GENERAL DESCRIPTION

Zilog's Z86C02/E02/L02 microcontrollers (MCUs) are members of the Z8[®] single-chip MCU family, which offer easy software/hardware system expansion.

For applications demanding powerful I/O capabilities, the MCU's dedicated input and output lines are grouped into

three ports, and are configurable under software control to provide timing, status signals, or parallel I/O.

One on-chip counter/timer, with a large number of user-selectable modes, off-load the system of administering realtime tasks such as counting/timing and I/O data communi-



GENERAL DESCRIPTION (Continued)

cations. Additionally, two on-board comparators process analog signals with a common reference voltage (Figure 1).

Note: All Signals with a preceding front slash, "/", are active Low, e.g.: B//W (WORD is active Low); /B/W (BYTE is active Low, only).

Power connections follow conventional descriptions below:

Connection	Circuit	Device
Power	V _{CC}	V_{DD}
Ground	GND	V_{SS}

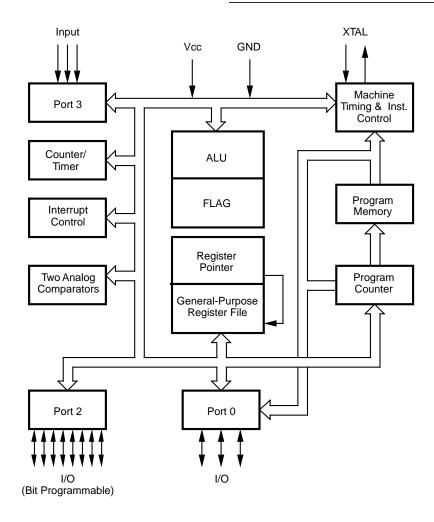


Figure 1. Z86C02/E02/L02 Functional Block Diagram



GENERAL DESCRIPTION (Continued)

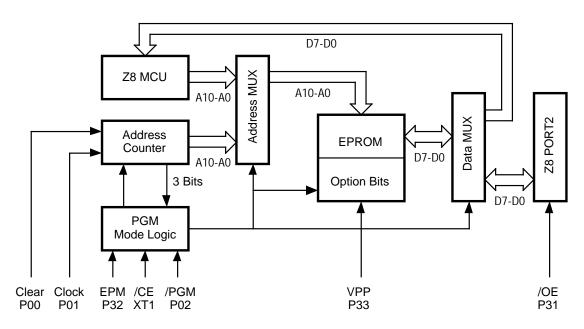


Figure 2. EPROM Programming Mode Block Diagram

PIN DESCRIPTIONS

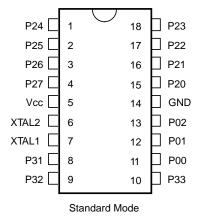


Figure 3. 18-Pin Standard Mode Configuration

Table 1. 18-Pin Standard Mode Identification

Pin#	Symbol	Function	Direction
1-4	P24-P27	Port 2, Pins 4, 5, 6, 7	In/Output
5	V _{CC}	Power Supply	
6	XTAL2	Crystal Oscillator Clock	Output
7	XTAL1	Crystal Oscillator Clock	Input
8	P31	Port 3, Pin 1, AN1	Input
9	P32	Port 3, Pin 2, AN2	Input
10	P33	Port 3, Pin 3, REF	Input
11-13	P00-P02	Port 0, Pins 0, 1, 2	In/Output
14	GND	Ground	
15-18	P20-P23	Port 2, Pins 0, 1, 2, 3	In/Output

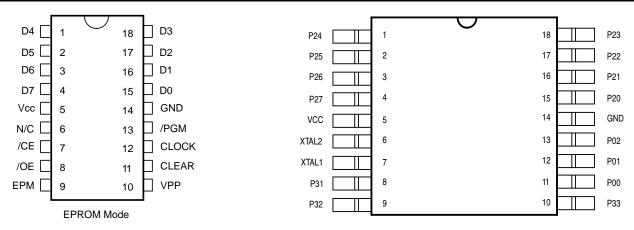


Figure 4. 18-Pin EPROM Mode Configuration

Table 2. 18-Pin EPROM Mode Identification

Pin #	Symbol	Function	Direction
1-4	D4-D7	Data 4, 5, 6, 7	In/Output
5	Vcc	Power Supply	
6	NC	No Connection	
7	/CE	Chip Enable	Input
8	/OE	Output Enable	Input
9	EPM	EPROM Program	Input
		Mode	
10	VPP	Program Voltage	Input
11	Clear	Clear Clock	Input
12	Clock	Address	Input
13	/PGM	Program Mode	Input
14	GND	Ground	
15-18	D0-D3	Data 0, 1, 2, 3	In/Output

Figure 5. 18-Pin SOIC Configuration

Table 3. 18-Pin SOIC Pin Identification

	Standard Mode										
Pin#	Symbol	Function	Direction								
1-4	P24-P27	Port 2, Pins	In/Output								
		4,5,6,7									
5	Vcc	Power Supply									
6	XTAL2	Crystal Osc. Clock	Output								
7	XTAL1	Crystal Osc. Clock	Input								
8	P31	Port 3, Pin 1, AN1	Input								
9	P32	Port 3, Pin 2, AN2	Input								
10	P33	Port 3, Pin 3, REF	Input								
11-13	P00-P02	Port 0, Pins 0,1,2	In/Output								
14	GND	Ground									
15-18	P20-P23	Port 2, Pins	In/Output								
		0,1,2,3									



ABSOLUTE MAXIMUM RATINGS

Parameter	Min	Max	Units
Ambient Temperature under Bias	-40	+105	С
Storage Temperature	- 65	+150	С
Voltage on any Pin with Respect to V _{SS} [Note 1]	-0.7	+12	V
Voltage on V _{DD} Pin with Respect to V _{SS}	-0.3	+7	V
Voltage on Pin 7 with Respect to V _{SS} [Note 2] (Z86C02/L02)	-0.7	V _{DD} +1	V
Voltage on Pin 7,8,9,10 with Respect to V _{SS} [Note 2] (Z86E02)	-0.7	V _{DD} +1	V
Total Power Dissipation		462	mW
Maximum Allowed Current out of V _{SS}		300	mA
Maximum Allowed Current into V _{DD}		270	mA
Maximum Allowed Current into an Input Pin [Note 3]	-600	+600	μΑ
Maximum Allowed Current into an Open-Drain Pin [Note 4]	-600	+600	μΑ
Maximum Allowed Output Current Sinked by Any I/O Pin		20	mA
Maximum Allowed Output Current Sourced by Any I/O Pin		20	mA
Maximum Allowed Output Current Sinked by Port 2, Port 0		80	mA
Maximum Allowed Output Current Sourced by Port 2, Port 0		80	mA

Notes:

Stresses greater than those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at any condition above those indicated in the operational sections of these specifications is not implied. Exposure to absolute maximum rating conditions for an extended period may affect device reliability.

Total power dissipation should not exceed 462 mW for the package. Power dissipation is calculated as follows:

- 1. This applies to all pins except where otherwise noted.
- 2. Maximum current into pin must be $\pm 600 \mu A$. There is no input protection diode from pin to V_{DD} .
- 3. This excludes Pin 6 and Pin 7.
- 4. Device pin is not at an output Low state.

Total Power dissipation = $V_{DD} \times [I_{DD} - (sum of I_{OH})] + sum of [(V_{DD} - V_{OH}) \times I_{OH}] + sum of (V_{0L} \times I_{0L})$

STANDARD TEST CONDITIONS

The characteristics listed below apply for standard test conditions as noted. All voltages are referenced to Ground. Positive current flows into the referenced pin (Figure 6).

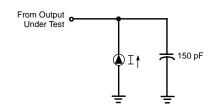


Figure 6. Test Load Diagram

CAPACITANCE

 $T_A = 25$ °C, $V_{CC} = GND = 0V$, f = 1.0 MHz, unmeasured pins returned to GND.

Parameter	Min	Max
Input capacitance	0	15 pF
Output capacitance	0	20 pF
I/O capacitance	0	25 pF



DC ELECTRICAL CHARACTERISTICS

Z86C02

				to +105°C to +70°C	Typical			
Sym.	Parameter	V _{CC} [4]	Min	Max	@ 25°C	Units	Conditions	Notes
V _{CH}	Clock Input High Voltage	3.0V	0.8 V _{CC}	V _{CC} +0.3	1.7	V	Driven by External Clock Generator	
		5.5V	0.8 V _{CC}	V _{CC} +0.3	2.8	V	Driven by External Clock Generator	
V _{CL}	Clock Input Low Voltage	3.0V	V _{SS} -0.3	0.2 V _{CC}	0.8	V	Driven by External Clock Generator	
		5.5V	V _{SS} -0.3	0.2 V _{CC}	1.7	V	Driven by External Clock Generator	
V _{IH}	Input High Voltage	3.0V	0.7 V _{CC}	V _{CC} +0.3	1.8	V		[1]
		5.5V	0.7 V _{CC}	V _{CC} +0.3	2.8	V		[1]
V _{IL}	Input Low Voltage	3.0V	V _{SS} -0.3	0.2 V _{CC}	0.8	V		[1]
		5.5V	V _{SS} -0.3	0.2 V _{CC}	1.5	V		[1]
V _{OH}	Output High Voltage	3.0V	V _{CC} -0.4		3.0	V	$I_{OH} = -2.0 \text{ mA}$	[5]
		5.5V	V _{CC} -0.4		4.8	V	$I_{OH} = -2.0 \text{ mA}$	[5]
		3.0V	V _{CC} -0.4		3.0	V	Low Noise @ I _{OH} = -0.5 mA	
		5.5V	V _{CC} -0.4		4.8	V	Low Noise @ I _{OH} = -0.5 mA	
V _{OL1}	Output Low Voltage	3.0V		0.8	0.2	V	I _{OL} = +4.0 mA	[5]
		5.5V		0.4	0.1	V	$I_{OL} = +4.0 \text{ mA}$	[5]
		3.0V		0.8	0.2	V	Low Noise @ I _{OL} = 1.0 mA	
		5.5V		0.4	0.1	V	Low Noise @ I _{OL} = 1.0 mA	
V _{OL2}	Output Low Voltage	3.0V		1.0	0.8	V	I _{OL} = +12 mA	[5]
		5.5V		0.8	0.3	V	I _{OL} = +12 mA	[5]
V _{OFFSET}	Comparator Input	3.0V		25	10	mV		
	Offset Voltage	5.5V		25	10	mV		
V_{LV}	V _{CC} Low Voltage					V		
	Auto Reset		2.2	2.8	2.6	V		[9]
	land Lankson	0.01/	2.0	3.0	2.6	V	\/ 0\/ \/	[10]
I _{IL}	Input Leakage (Input Bias Current	3.0V	-1.0	1.0		μΑ	$V_{IN} = 0V, V_{CC}$	
	of Comparator)	5.5V	-1.0	1.0		μΑ	$V_{IN} = 0V, V_{CC}$	
I _{OL}	Output Leakage	3.0V	-1.0	1.0		μΑ	$V_{IN} = 0V, V_{CC}$	
		5.5V	-1.0	1.0		μΑ	$V_{IN} = 0V, V_{CC}$	
V _{VICR}	Comparator Input		V _{SS} -0.3	V _{CC} -1.0		V		[9]
	Common Mode Voltage Range		V _{SS} -0.3	V _{CC} –1.5		V		[10]



DC CHARACTERISTICS

Z86C02

			T _A = 40°C	to+105°C				
			$T_A = 0^{\circ}C$	to +70°C	Typical			
Sym.	Parameter	V _{CC} [4]	Min	Max	@ 25°C	Units	Conditions	Notes
Icc	Supply Current	3.0V		3.5	1.5	mA	@ 2 MHz	[5,6,7]
		5.5V		7.0	3.8	mA	@ 2 MHz	[5,6,7]
		3.0V		8.0	3.0	mA	@ 8 MHz	[5,6,7]
		5.5V		11.0	4.4	mA	@ 8 MHz	[5,6,7]
I _{CC1}	Standby Current (Halt Mode)	3.0V		2.5	0.7	mA	@ 2 MHz	[5,6,7]
		5.5V		4.0	2.5	mA	@ 2 MHz	[5,6,7]
		3.0V		4.0	1.0	mA	@ 8 MHz	[5,6,7]
		5.5V		5.0	3.0	mA	@ 8 MHz	[5,6,7]
I _{CC}	Supply Current (Low Noise Mode)	3.0V		3.5	1.5	mA	@ 1 MHz	[5,6,7]
		5.5V		7.0	3.8	mA	@ 1 MHz	[5,6,7]
		3.0V		5.8	2.5	mA	@ 2 MHz	[5,6,7]
		5.5V		9.0	4.0	mA	@ 2 MHz	[5,6,7]
		3.0V		8.0	3.0	mA	@ 4 MHz	[5,6,7]
		5.5V		11.0	4.4	mA	@ 4 MHz	[5,6,7]
I _{CC1}	Standby Current	3.0V		2.5	0.7	mA	@ 1 MHz	[6,7,8]
	(Low Noise Halt Mode)	5.5V		4.0	2.5	mA	@ 1 MHz	[6,7,8]
		3.0V		3.0	0.9	mA	@ 2 MHz	[6,7,8]
		5.5V		4.5	2.8	mA	@ 2 MHz	[6,7,8]
		3.0V		4.0	1.0	mA	@ 4 MHz	[6,7,8]
		5.5V		5.0	3.0	mA	@ 4 MHz	[6,7,8]
I _{CC2}	Standby Current (Stop Mode)	3.0V		10	1.0	μΑ		[6,7,8,9]
		3.0V		20	1.0	μΑ		[6,7,8,10]
		5.5V		10	1.0	μΑ		[6,7,8,9]
		5.5V		20	1.0	μΑ		[6,7,8,10]
I _{ALL}	Auto Latch Low Current	3.0V		12	3.0	μΑ	0V < V _{IN} < V _{CC}	
		5.5V		32	16	μΑ	0V < V _{IN} < V _{CC}	
I _{ALH}	Auto Latch High Current	3.0V		-8	-1.5	μΑ	$0V < V_{IN} < V_{CC}$	
		5.5V		-16	-8.0	μΑ	$0V < V_{IN} < V_{CC}$	

Notes:

- 1. ort 0, 2, and 3 only.
- 2. $V_{SS} = 0V = GND$.
- 3. The device operates down to V_{LV} The minimum operational V_{CC} is determined on the value of the voltage V_{LV} at the ambient temperature.
- 4. V_{CC} = 3.0V to 5.5V, typical values measured at V_{CC} = 3.3V and V_{CC} = 5.0V.
- 5. Standard mode (not Low EMI mode).
- 6. Inputs at V_{CC} or V_{SS} , outputs unloaded.
- 7. Halt mode and Low EMI mode.
- 8. WDT not running.
- 9. $T_A = 0^{\circ}C$ to $70^{\circ}C$.
- 10. $T_A = 40^{\circ}C$ to $105^{\circ}C$.



DC CHARACTERISTICS

Z86L02

			$T_A = 0^{\circ}C$	to +70°C	Typical			
Sym.	Parameter	V _{CC} [4]	Min	Max	@ 25°C	Units	Conditions	Notes
V_{CH}	Clock Input High Voltage	2.0V	0.9 V _{CC}	V _{CC} +0.3		V	Driven by External Clock Generator	
	_	3.9V	0.9 V _{CC}	V _{CC} +0.3		V	Driven by External Clock Generator	
V_{CL}	Clock Input Low Voltage	2.0V	V _{SS} -0.3	0.1 V _{CC}		V	Driven by External Clock Generator	
	-	3.9V	V _{SS} -0.3	0.1 V _{CC}		V	Driven by External Clock Generator	
V _{IH}	Input High Voltage	2.0V	0.9 V _{CC}	V _{CC} +0.3		V		[1]
	-	3.9V	0.9 V _{CC}	V _{CC} +0.3		V		[1]
V_{IL}	Input Low Voltage	2.0V	V _{SS} -0.3	0.1 V _{CC}		V		[1]
	-	3.9V	V _{SS} -0.3	0.1 V _{CC}		V		[1]
V _{OH}	Output High Voltage	2.0V	V _{CC} -0.4		3.0	V	$I_{OH} = -500 \mu A$	[5]
	-	3.9V	V _{CC} -0.4		3.0	V	$I_{OH} = -500 \mu A$	[5]
V _{OL1}	Output Low Voltage	2.0V		0.8	0.2	V	$I_{OL} = +1.0 \text{ mA}$	[5]
	-	3.9V		0.4	0.1	V	$I_{OL} = +1.0 \text{ mA}$	[5]
V_{OL2}	Output Low Voltage	2.0V		1.0	0.8	V	$I_{OL} = + 3.0 \text{ mA}$	[5]
	-	3.9V		0.8	0.3	V	$I_{OL} = + 3.0 \text{ mA}$	[5]
V _{OFFSET}	Comparator Input	2.0V		25	10	mV		
	Offset Voltage	3.9V		25	10	mV		
V_{LV}	V _{CC} Low Voltage Auto Reset		1.4	2.15		V		
I _{IL}	Input Leakage	2.0V	-1.0	1.0		μΑ	$V_{IN} = 0V, V_{CC}$	
	(Input Bias Current of Comparator)	3.9V	-1.0	1.0		μΑ	$V_{IN} = 0V, V_{CC}$	
I_{OL}	Output Leakage	2.0V	-1.0	1.0		μA	$V_{IN} = 0V, V^{CC}$	
	-	3.9V	-1.0	1.0		μΑ	$V_{IN} = 0V, V_{CC}$	
V _{VICR}	Comparator Input Common Mode Voltage Range		V _{SS} -0.3	V _{CC} -1.0		V		



			T _A = 0°C	to +70°C	Typical			
Sym	Parameter	V _{CC} [4]	Min	Max	@ 25°C	Units	Conditions	Notes
Icc	Supply Current	2.0V		3.3		mA	@ 2 MHz	[5,6]
		3.9V		6.8		mA	@ 2 MHz	[5,6]
		2.0V		6.0		mA	@ 8 MHz	[5,6]
		3.9V		9.0		mA	@ 8 MHz	[5,6]
I _{CC1}	Standby Current (Halt Mode)	2.0V		2.3		mA	@ 2 MHz	[5,6,7]
		3.9V		3.8		mA	@ 2 MHz	[5,6,7]
		2.0V		3.8		mA	@ 8 MHz	[5,6,7]
		3.9V		4.8		mA	@ 8 MHz	[5,6,7]
I _{CC2}	Standby Current (Stop Mode)	2.0V		10	1.0	μΑ		[6,7]
		3.9V		10	1.0	μΑ		[6,7]
I _{ALL}	Auto Latch Low Current	2.0V		12	3.0	μΑ	$0V < V_{IN} < V_{CC}$	
		3.9V		32	16	μΑ	$0V < V_{IN} < V_{CC}$	
I _{ALH}	Auto Latch High Current	2.0V		-8	-1.5	μΑ	$0V < V_{IN} < V_{CC}$	
		3.9V		-16	-8.0	μΑ		

Notes:

- 1. Port 0, 2, and 3 only
- 2. $V_{SS} = 0V = GND$. The device operates down to V_{LV} . The minimum operational V_{CC} is determined by the value of the voltage V_{LV} at the ambient temperature.
- 3. V_{CC} = 2.0V to 3.9V, typical values measured at V_{CC} = 3.3 V.
- 4. Standard Mode (not Low EMI mode).
- 5. Inputs at $\rm V_{CC}$ or $\rm V_{SS},$ outputs are unloaded.
- 6. WDT is not running.



DC CHARACTERISTICS

Z86E02

			$T_A = -40^{\circ}C$	c to +105°C				
		., .,		to +70°C	Typical			
Sym.	Parameter	V _{CC} [4]	Min	Max	@ 25°C	Units	Conditions	Notes
V _{CH}	Clock Input High Voltage	4.5V	0.8 V _{CC}	V _{CC} +0.3	2.8	V	Driven by External Clock Generator	
		5.5V	0.8 V _{CC}	V _{CC} +0.3	2.8	V	Driven by External Clock Generator	
V _{CL}	Clock Input Low Voltage	4.5V	V _{SS} -0.3	0.2 V _{CC}	1.7	V	Driven by External Clock Generator	
		5.5V	V _{SS} _0.3	0.2 V _{CC}	1.7	V	Driven by External Clock Generator	
V _{IH}	Input High Voltage	4.5V	0.7 V _{CC}	V _{CC} +0.3	2.8	V		
		5.5V	0.7 V _{CC}	V _{CC} +0.3	2.8	V		
V _{IL}	Input Low Voltage							
		5.5V	V _{SS} -0.3	0.2 V _{CC}	1.5	V		
V _{OH}	Output High Voltage	4.5V	V _{CC} -0.4		4.8	V	$I_{OH} = -2.0 \text{ mA}$	[5]
		5.5V	V _{CC} -0.4		4.8	V	$I_{OH} = -2.0 \text{ mA}$	[5]
		4.5V	V _{CC} -0.4		4.8	V	Low Noise @	
		5.5V	V _{CC} -0.4		4.8	V	$I_{OH} = -0.5 \text{ mA}$	
V _{OL1}	Output Low Voltage	4.5V		0.4	0.1	V	$I_{OL} = +4.0 \text{ mA}$	[5]
		5.5V		0.4	0.1	V	$I_{OL} = +4.0 \text{ mA}$	[5]
		4.5V		0.4	0.1	V	Low Noise @ I _{OL} = 1.0 mA	
		5.5V		0.4	0.1	V	Low Noise @ I _{OL} = 1.0 mA	
V _{OL2}	Output Low Voltage	4.5V		1.0	0.8	V	I _{OL} = +12 mA	[5]
		5.5V		1.0	0.8	V	I _{OL} = +12 mA	[5]
V _{OFFSET}	Comparator Input	4.5V		25	10	mV		
	Offset Voltage	5.5V		25	10	mV		
V_{LV}	V _{CC} Low Voltage		2.6	3.3	3.0	V		[9]
	Auto Reset		2.2	3.6	3.0	V		[10]
I _{IL}	Input Leakage (Input	4.5V	-1.0	1.0		μΑ	$V_{IN} = 0V, V_{CC}$	
	Bias Current of Comparator)	5.5V	-1.0	1.0		μΑ	$V_{IN} = 0V, V_{CC}$	
I_{OL}	Output Leakage	4.5V	-1.0	1.0		μΑ	$V_{IN} = 0V, V_{CC}$	
		5.5V	-1.0	1.0		μΑ	$V_{IN} = 0V, V_{CC}$	
V _{VICR}	Comparator Input Common Mode		V _{SS} -0.3	V _{CC} –1.0		V		[9]
	Voltage Range		V _{SS} -0.3	V _{CC} –1.5		V		[10]



No				• •	to +105°C to +70°C	Typical			
Simply Current (HALT mode) Simply Current (Low Noise) Halt Mode) Halt Mode	Sym.	Parameter	V _{CC} [4]	Min	Max	@ 25°C	Units	Conditions	Notes
15.0	I _{CC}	Supply Current	4.5V		9.0	3.8	mΑ	@ 2 MHz	[5,6]
Standby Current (HALT mode) 4.5V 4.0 2.5 mA @ 2 MHz Standby Current (HALT mode) 4.5V 4.0 2.5 mA @ 2 MHz Standby Current (Low Noise 4.5V 5.0 3.0 mA @ 4 MHz Standby Current (Low Noise 4.5V 9.0 3.8 mA Standby Current (Low Noise 4.5V 9.0 3.8 mA Standby Current (Low Noise 4.5V 9.0 3.8 mA Standby Current (Low Noise 4.5V 11.0 4.0 mA @ 2 MHz Standby Current (Low Noise 4.5V 11.0 4.0 mA @ 2 MHz Standby Current (Low Noise 4.5V 15.0 4.4 mA @ 4 MHz Standby Current (Low Noise 4.5V 15.0 4.4 mA @ 4 MHz Standby Current (Low Noise 4.5V 4.0 2.5 mA @ 1 MHz Standby Current (Low Noise 4.5V 4.0 2.5 mA @ 1 MHz Standby Current (Low Noise 4.5V 4.5 2.7 mA @ 2 MHz Standby Current (Stop Mode) 4.5V 4.5 2.7 mA @ 2 MHz Standby Current (Stop Mode) 4.5V 5.0 3.0 mA @ 4 MHz Standby Current (Stop Mode) 4.5V 10 1.0 µA Standby Current (Stop Mode) 4.5V 20 1.0 µA Standby Current (Stop Mode) 4.5V 20 1.0 µA Standby Current (Stop Mode) 4.5V 20 1.0 µA Standby Current (Stop Mode) 4.5V 32 16 µA 0V <v<sub>IN<v<sub>ICC Standby Current (Stop Mode) 4.5V 32 16 µA 0V <v<sub>IN<v<sub>ICC Standby Current (Stop Mode) 4.5V 32 16 µA 0V <v<sub>IN<v<sub>ICC Standby Current (Stop Mode) 4.5V 32 16 µA 0V <v<sub>IN<v<sub>ICC Standby Current (Stop Mode) 4.5V 32 16 µA 0V <v<sub>IN<v<sub>ICC Standby Current (Stop Mode) 4.5V 32 16 µA 0V <v<sub>IN<v<sub>ICC Standby Current (Stop Mode) 4.5V 32 16 µA 0V <v<sub>IN<v<sub>ICC Standby Current (Stop Mode) 4.5V 32 16 µA 0V <v<sub>IN<v<sub>ICC Standby Current (Stop Mode) 4.5V 32 16 µA 0V <v<sub>IN<v<sub>ICC Standby Current (Stop Mode) 4.5V 32 16 µA 0V <v<sub>IN<v<sub>ICC Standby Current (Stop Mode) 4.5V 32 16 µA 0V <v<sub>IN<v<sub>ICC Standby Current (Stop Mode) 4.5V 32 16 µA 0V <v<sub>IN<v<sub>IC</v<sub></v<sub></v<sub></v<sub></v<sub></v<sub></v<sub></v<sub></v<sub></v<sub></v<sub></v<sub></v<sub></v<sub></v<sub></v<sub></v<sub></v<sub></v<sub></v<sub></v<sub></v<sub></v<sub></v<sub>			5.5V		9.0	3.8	mA	@ 2 MHz	[5,6]
ICC1 Standby Current (HALT mode) 4.5V 4.0 2.5 mA @ 2 MHz 5.5V 4.0 2.5 mA @ 2 MHz 4.5V 5.0 3.0 mA @ 4 MHz 5.5V 5.0 3.0 mA @ 4 MHz 5.5V 5.0 3.0 mA @ 4 MHz Mode) 4.5V 9.0 3.8 mA 4.5V 9.0 3.8 mA 4.5V 11.0 4.0 mA @ 2 MHz 5.5V 11.0 4.0 mA @ 2 MHz 4.5V 15.0 4.4 mA @ 4 MHz 5.5V 15.0 4.4 mA @ 4 MHz 1CC1 Standby Current (Low Noise 4.5V 4.0 2.5 mA @ 1 MHz 4.5V 4.5V 4.0 2.5 mA @ 1 MHz 4.5V 4.5V 4.5 2.7 mA @ 2 MHz 4.5V 5.0 3.0 mA			4.5V		15.0	4.4	mA	@ 8 MHz	[5,6]
S.5V 4.0 2.5 mA @ 2 MHz 4.5V 5.0 3.0 mA @ 4 MHz 5.5V 5.0 3.0 mA @ 4 MHz 5.5V 5.0 3.0 mA @ 4 MHz 5.5V 5.0 3.0 mA @ 4 MHz 6.5V 9.0 3.8 mA 6.5V 9.0 3.8 mA 6.5V 9.0 3.8 mA 6.5V 9.0 3.8 mA 7.5V 11.0 4.0 mA @ 2 MHz 7.5V 15.0 4.4 mA @ 4 MHz 7.5V 15.0 4.4 mA @ 1 MHz 7.5V 4.0 2.5 mA @ 1 MHz 7.5V 4.5 2.7 mA @ 2 MHz 7.5V 5.0 3.0 mA @ 4 MHz 7.5V 5.5V 5.0 5.0 5.0 5.0 5.0 7.5V 5.5V 5.0 5.0 5.0 5.0 5.0 5.0 7.5V 5.5V 5.0 5.0 5.0 5.0 5.0 5.0 7.5V 5.0V 5.0V 5.0V 5.0 5.0 5.0 5.0 7.5V 5.5V 5.0V			5.5V		15.0	4.4	mΑ	@ 1 MHz	[5,6]
Harmon	I _{CC1}	Standby Current (HALT mode)	4.5V		4.0	2.5	mA	@ 2 MHz	[5,6]
Supply Current (Low Noise			5.5V		4.0	2.5	mA	@ 2 MHz	[5,6]
Supply Current (Low Noise Mode) 4.5V 9.0 3.8 mA			4.5V		5.0	3.0	mA	@ 4 MHz	[5,6]
Mode S.5V 9.0 3.8 mA 4.5V 11.0 4.0 mA @ 2 MHz 5.5V 11.0 4.0 mA @ 2 MHz 5.5V 11.0 4.0 mA @ 2 MHz 4.5V 15.0 4.4 mA @ 4 MHz 5.5V 15.0 4.4 mA @ 4 MHz 5.5V 15.0 4.4 mA @ 4 MHz 6.5V 15.0 4.4 mA @ 4 MHz 1.0V 4.0 2.5 mA @ 1 MHz 1.0V 4.5V 4.0 2.5 mA @ 1 MHz 4.5V 4.5 2.7 mA @ 2 MHz 4.5V 4.5 2.7 mA @ 2 MHz 5.5V 4.5 2.7 mA @ 2 MHz 4.5V 5.0 3.0 mA @ 4 MHz 4.5V 5.0 3.0 mA @ 4 MHz 1.0V 4.5V 5.0 3.0 mA @ 4 MHz 1.0V 4.5V 10 1.0 μA 1.0V 4.5V 20 1.0 μA 1.0V 4.5V 32 16 μA 0V 4.5V 1.0V 4.5V 6.5V 6.5V 6.5V 6.5V 6.5V 1.0V 4.5V 6.5V 6.5V 6.5V 6.5V 6.5V 6.5V 1.0V 4.5V 6.5V			5.5V		5.0	3.0	mA	@ 4 MHz	[5,6]
A.5V 11.0 A.0 mA @ 2 MHz 5.5V 11.0 A.0 mA @ 2 MHz 4.5V 15.0 A.4 mA @ 4 MHz 5.5V 15.0 A.4 mA @ 4 MHz 5.5V 15.0 A.4 mA @ 4 MHz 6.5V A.0 2.5 mA @ 1 MHz 7.5V A.0 2.5 mA @ 1 MHz 8.5V A.0 2.5 mA @ 1 MHz 9.5V A.5 2.7 mA @ 2 MHz 1.5V A.5 3.0 mA @ 4 MHz 1.5V A.5 3.0 mA @ 4 MHz 1.5V A.5 A.5 A.5 1.5V A.5 A.5 A.5 1.5V A.5 A.5 A.5 1.5V A.5 1	I _{CC}	Supply Current (Low Noise	4.5V		9.0	3.8	mA		[6]
Standby Current (Low Noise Halt Mode) H		Mode)	5.5V		9.0	3.8	mA		[6]
A.5V 15.0 4.4 mA @ 4 MHz 5.5V 15.0 4.4 mA @ 4 MHz 1			4.5V		11.0	4.0	mA	@ 2 MHz	[6]
Standby Current (Low Noise Halt Mode)			5.5V		11.0	4.0	mA	@ 2 MHz	[6]
Standby Current (Low Noise Halt Mode)			4.5V		15.0	4.4	mA	@ 4 MHz	[6]
Halt Mode 5.5V 4.0 2.5 mA @ 1 MHz 4.5V 4.5 2.7 mA @ 2 MHz 5.5V 4.5 2.7 mA @ 2 MHz 5.5V 5.0 3.0 mA @ 4 MHz 5.5V 5.0 3.0 mA @ 4 MHz 5.5V 5.0 3.0 mA @ 4 MHz 6.5V 5.0 3.0 mA @ 4 MHz 6.5V 10 1.0 μA 6.5V 20 1.0 μA 6.5V 20 1.0 μA 7.5V 32 16 μA 0V < V _{IN} < V _{CC} 7.5V 32 16 μA 0V < V _{IN} < V _{CC} 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5V 7.5			5.5V		15.0	4.4	mA	@ 4 MHz	[6]
A.5V A.5 2.7 mA @ 2 MHz 5.5V 4.5 2.7 mA @ 2 MHz 4.5V 5.0 3.0 mA @ 4 MHz 5.5V 5.0 3.0 mA @ 4 MHz 5.5V 5.0 3.0 mA @ 4 MHz 6.5V 10 1.0 μA 4.5V 20 1.0 μA 5.5V 10 1.0 μA 5.5V 20 1.0 μA 5.5V 20 1.0 μA 6.5V 20 1.0 μA 7	I _{CC1}	` `	4.5V		4.0	2.5	mA	@ 1 MHz	[6,7,8]
Solution		Halt Mode)	5.5V		4.0	2.5	mA	@ 1 MHz	[6,7,8]
4.5V 5.0 3.0 mA @ 4 MHz 5.5V 5.0 3.0 mA @ 4 MHz 1 _{CC2} Standby Current (Stop Mode) 4.5V 10 1.0 μA 4.5V 20 1.0 μA 5.5V 10 1.0 μA 5.5V 20 1.0 μA 1 _{ALL} Auto Latch Low Current 4.5V 32 16 μA 0V < V _{IN} < V _{CC} 5.5V 32 16 μA 0V < V _{IN} < V _{CC} ALH Auto Latch High 4.5V -16 -8.0 μA 0V < V _{IN} < V _{CC}			4.5V		4.5	2.7	mA	@ 2 MHz	[6,7,8]
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$			5.5V		4.5	2.7	mA	@ 2 MHz	[6,7,8]
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$			4.5V		5.0	3.0	mA	@ 4 MHz	[6,7,8]
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$			5.5V		5.0	3.0	mA	@ 4 MHz	[6,7,8]
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	I _{CC2}	Standby Current (Stop Mode)	4.5V		10	1.0	μΑ		[6,7,9]
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$			4.5V		20	1.0	μΑ		[6,7,10]
I_{ALL} Auto Latch Low Current 4.5V 32 16 μA $0V < V_{IN} < V_{CC}$ 5.5V 32 16 μA $0V < V_{IN} < V_{CC}$ ALH Auto Latch High 4.5V -16 -8.0 μA $0V < V_{IN} < V_{CC}$			5.5V		10	1.0	μΑ		[6,7,9]
			5.5V		20	1.0	μΑ		6,7,10]
ALH Auto Latch High 4.5V -16 -8.0 μA 0V $<$ V $_{IN}<$ V $_{CC}$	I _{ALL}	Auto Latch Low Current	4.5V		32	16	μΑ		
			5.5V		32	16	μΑ	$0V < V_{IN} < V_{CC}$	
5.5V -16 -8.0 UA 0V -VV.c.	ALH	Auto Latch High	4.5V		-16	-8.0	μΑ	0V <v<sub>IN<v<sub>CC</v<sub></v<sub>	
2.5 v 10 0.0 μ/ν 0 v v IN v CC			5.5V		-16	-8.0	μΑ	0V <v<sub>IN<v<sub>CC</v<sub></v<sub>	

Notes:

- 1. Port 0, 2, and 3 only.
- 2. $V_{SS} = 0V = GND$.
- 3. The device operates down to V_{LV} of the specified frequency for V_{LV} . The minimum operational V_{CC} is determined by the value of the voltage V_{LV} at the ambient temperature.
- 4. The V_{LV} increases as the temperature decreases.
- 5. $V_{CC} = 4.5V$ to 5.5V, typical values measured at $V_{CC} = 5.0V$.
- 6. Standard mode (not Low EMI mode).
- 7. Inputs at V_{CC} or V_{SS}, outputs unloaded.
- 8. WDT not running.
- 9. Halt mode and Low EMI mode.
- 10. $T_A = 0$ °C to 70°C. $T_A = -40$ °C to 105°C.

DS96DZ80301 (11/96) PRELIMINARY 1-11



AC ELECTRICAL CHARACTERISTICS

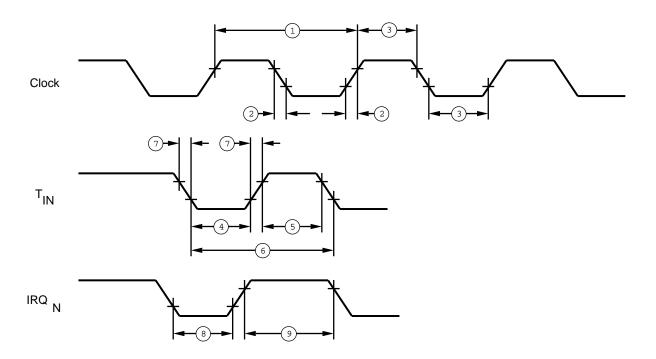


Figure 7. AC Electrical Timing Diagram



AC ELECTRICAL CHARACTERISTICS

Timing Table (Standard Mode for SCLK/TCLK = XTAL/2)

$T_A = -40^{\circ}C \text{ to } +105^{\circ}C$
$T_A = 0^{\circ}C$ to $+70^{\circ}C$
8 MHz

			8 IVITZ				
No.	Symbol	Parameter	v_{cc}	Min	Max	Units	Notes
1	ТрС	Input Clock Period	2.0V	125	DC	ns	[1]
		_	5.5V	125	DC	ns	[1]
2	TrC,TfC	Clock Input Rise and Fall Times	2.0V		25	ns	[1]
		_	5.5V		25	ns	[1]
3	TwC	Input Clock Width	2.0V	62		ns	[1]
			5.5V	62		ns	[1]
4	TwTinL	Timer Input Low Width	2.0V	70		ns	[1]
			5.5V	70		ns	[1]
5	TwTinH	Timer Input High Width	2.0V	5TpC			[1]
			5.5V	5TpC			[1]
6	TpTin	Timer Input Period	2.0V	8TpC			[1]
			5.5V	8TpC			[1]
7	TrTin,	Timer Input Rise and Fall Time	2.0V		100	ns	[1]
	TtTin		5.5V		100	ns	[1]
8	TwIL	Int. Request Input Low Time	2.0V	70		ns	[1,2,3]
			5.5V	70		ns	[1,2,3]
9	TwIH	Int. Request Input High Time	3.0V	5TpC			[1,2,3]
			5.5V	5TpC			[1,2,3]
10	Twdt	Watch-Dog Timer Delay Time Before Time-Out	2.0V	25		ms	
			3.0V	10		ms	
			5.5V	5		ms	
11	Tpor	Power-On Reset Time	2.0V	70	250	ms	[4]
			3.0V	50	150	ms	[4]
		_	5.5V	10	70	ms	[4]
		_	2.0V	8	76	ms	[5]
		_	3.0V	4	38	ms	[5]
			5.5V	2	18	ms	[5]

Notes:

- 1. Timing Reference uses 0.7 $\rm V_{CC}$ for a logic 1 and 0.2 $\rm V_{CC}$ for a logic 0.
- 2. Interrupt request through Port 3 (P33-P31).
- 3. IRQ 0,1,2 only.
- 4. Z86E02 only.
- 5. Z86C02/L02 only.



AC ELECTRICAL CHARACTERISTICS

Low Noise Mode (Z86C02/E02 Only)

			T _A = -40°C to +105°C						
				4 5 5		to +70°C			
No.	Symbol	Parameter	v_{cc}	1 M Min	Hz Max	4 M Min	Hz Max	Units	Notes
1	TPC	Input Clock Period	3.0V	1000	DC	250	DC	ns	[1]
			5.5V	1000	DC	250	DC	ns	[1]
2	TrC	Clock Input Rise and Fall Times	3.0V		25		25	ns	[1]
	TfC		5.5V		25		25	ns	[1]
3	TwC	Input Clock Width	3.0V	500		125		ns	[1]
			5.5V	500		125		ns	[1]
4.	TwTinL	Timer Input Low Width	3.0V	70		70		ns	[1]
			5.5V	70		70		ns	[1]
5	TwTinH	Timer Input High Width	3.0V	2.5TpC		2.5TpC			[1]
		_	5.5V	2.5TpC		2.5TpC			[1]
6	TpTin	Timer Input Period	3.0V	4TpC		4TpC			[1]
		_	5.5V	4TpC		4TpC			[1]
7	TrTin,	Timer Input Rise and Fall Time	3.0V		100		100	ns	[1]
	TtTin	-	5.5V		100		100	ns	[1]
8	TwlL	Int. Request Input Low Time	3.0V	70		70		ns	[1,2,3]
		_	5.5V	70		70		ns	[1,2,3]
9	TwlH	Int. Request Input High Time	3.0V	2.5TpC		2.5TpC			[1,2,3]
		_	5.5V	2.5TpC		2.5TpC			[1,2,3]
10	Tpor	Power-On Reset Time	3.0V	50	150	50	150	ms	[4]
		-	5.5V	10	70	10	70	ms	[4]
		_	2.0V	8	76	8	76	ms	[5]
		_	3.0V	4	38	4	38	ms	[5]
			5.5V	2	18	2	18	ms	[5]
11	Twdt	Watch-Dog Timer Delay	3.0V	10		10		ms	
		_	5.5V	5		5		ms	

Notes:

- 1. Timing Reference uses 0.7 $\rm V_{CC}$ for a logic 1 and 0.2 $\rm V_{CC}$ for a logic 0.
- 2. Interrupt request through Port 3 (P33-P31).
- 3. IRQ 0,1,2 only.
- 4. Z86E02 only.
- 5. Z86C02/L02 only.



LOW NOISE VERSION

Low EMI Emission

The Z8 can be programmed to operate in a Low EMI emission mode by means of a mask ROM bit option (Z86C02) or OTP bit option (Z86E02). Use of this feature results in:

- All pre-driver slew rates reduced to 10 ns typical.
- Internal SCLK/TCLK operation limited to a maximum of 4 MHz - 250 ns cycle time.
- Output drivers have resistances of 200 ohms (typical).
- Oscillator divide-by-two circuitry eliminated.

The Low EMI mode is mask-programmable to be selected by the customer at the time the ROM Code is submitted (for Z86C02 only).

PRECAUTION

Stack pointer register (SPL) at FFHex and general purpose register at FEHex are set to 00Hex after reset.

PIN FUNCTIONS

OTP Programming Mode

D7-D0 Data Bus. Data can be read from, or written to the EPROM through this data bus.

V_{CC} Power Supply. It is 5V during EPROM Read Mode and 6.4V during the other modes (Program, Program Verify, etc.).

/CE Chip Enable (active Low). This pin is active during EPROM Read Mode, Program Mode, and Program Verify Mode.

/OE Output Enable (active Low). This pin drives the Data Bus direction. When this pin is Low, the Data Bus is output. When High, the Data Bus is input. This pin must toggle for each data output read.

EPM EPROM Program Mode. This pin controls the different EPROM Program Modes by applying different voltages.

 $\mathbf{V_{PP}}$ Program Voltage. This pin supplies the program voltage.

Clear Clear (active High). This pin resets the internal address counter at the High Level.

Clock Address Clock. This pin is a clock input. The internal address counter increases by one with one clock cycle.

/PGM Program Mode (active Low). A Low level at this pin programs the data to the EPROM through the Data Bus.

Application Precaution

The production test-mode environment may be enabled accidentally during normal operation if **excessive noise** surges above V_{CC} occur on the XTAL1 pin.

In addition, processor operation of Z8 OTP devices may be affected by **excessive noise** surges on the V_{PP} , /CE, /EPM, /OE pins while the microcontroller is in Standard Mode.

Recommendations for dampening voltage surges in both test and OTP mode include the following:

- Using a clamping diode to V_{CC}.
- Adding a capacitor to the affected pin.



PIN FUNCTIONS (Continued)

XTAL1, XTAL2 Crystal In, Crystal Out (time-based input and output, respectively). These pins connect a parallel-resonant crystal, LC, RC, or an external single-phase clock (8 MHz max) to the on-chip clock oscillator and buffer.

Port 0, P02-P00. Port 0 is a 3-bit bi-directional, Schmitt-triggered CMOS compatible I/O port. These three I/O lines can be globally configured under software control to be inputs or outputs (Figure 8).

Auto Latch. The Auto Latch puts valid CMOS levels on all CMOS inputs (except P33, P32, P31) that are not externally driven. A valid CMOS level, rather than a floating node, reduces excessive supply current flow in the input buffer. On Power-up and Reset, the Auto Latch will set the ports to an undetermined state of 0 or 1. Default condition is Auto Latches enabled.

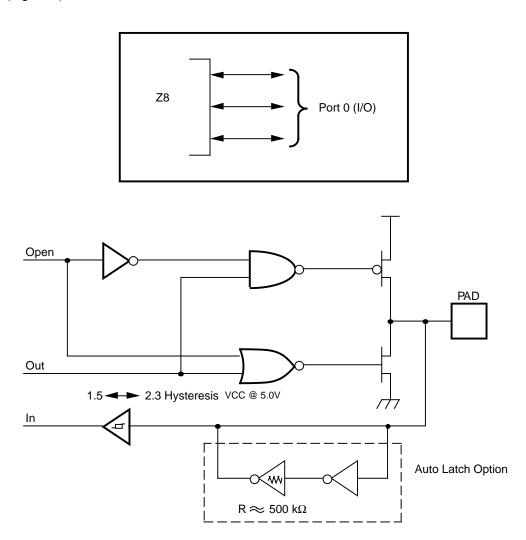
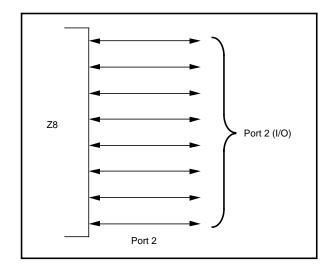


Figure 8. Port 0 Configuration

Port 2, P27-P20. Port 2 is an 8-bit, bit programmable, bidirectional, Schmitt-triggered CMOS compatible I/O port. These eight I/O lines can be configured under software

control to be inputs or outputs, independently. Bits programmed as outputs can be globally programmed as either push-pull or open-drain (Figure 9).



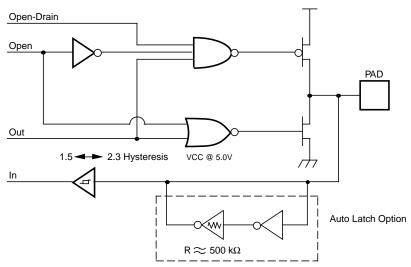


Figure 9. Port 2 Configuration



PIN FUNCTIONS (Continued)

Port 3, P33-P31. Port 3 is a 3-bit, CMOS compatible port with three fixed input (P33-P31) lines. These three input lines can be configured under software control as digital Schmitt-trigger inputs or analog inputs.

These three input lines are also used as the interrupt sources IRQ0-IRQ3 and as the timer input signal T_{IN} (Figure 10).

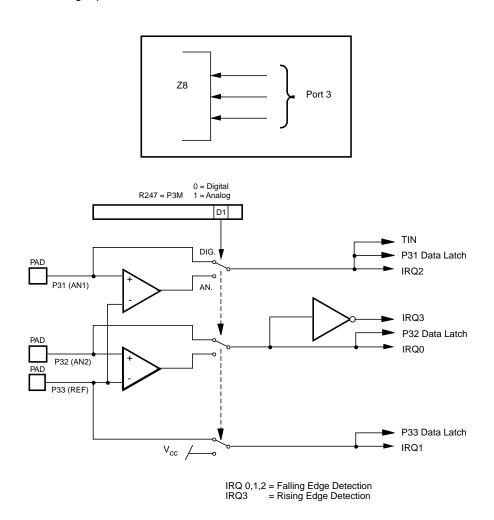


Figure 10. Port 3 Configuration

Comparator Inputs. Two analog comparators are added to input of Port 3, P31 and P32, for interface flexibility. The comparators reference voltage P33 (REF) is common to both comparators.

Typical applications for the on-board comparators; Zero crossing detection, A/D conversion, voltage scaling, and threshold detection. In analog mode, P33 input functions serve as a reference voltage to the comparators.

The dual comparator (common inverting terminal) features a single power supply which discontinues power in STOP mode. The common voltage range is 0-4 V when the $V_{\rm CC}$

is 5.0 V; the power supply and common mode rejection ratios are 90 dB and 60 dB, respectively.

Interrupts are generated on either edge of Comparator 2's output, or on the falling edge of Comparator 1's output. The comparator output is used for interrupt generation, Port 3 data inputs, or $T_{\rm IN}$ through P31. Alternatively, the comparators can be disabled, freeing the reference input (P33) for use as IRQ1 and/or P33 input.

FUNCTIONAL DESCRIPTION

The following special functions have been incorporated into the Z86C02/E02/L02 devices to enhance the standard Z8 core architecture to provide the user with increased design flexibility.

RESET. This function is accomplished by means of a Power-On Reset or a Watch-Dog Timer Reset. Upon power-up, the Power-On Reset circuit waits for T_{POR} ms, plus 18 clock cycles, then starts program execution at address 000C (Hex) (Figure 11). The control registers' reset value is shown in Table 4.

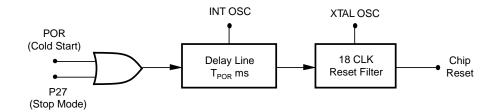


Figure 11. Internal Reset Configuration

Power-On Reset (POR). A timer circuit clocked by a dedicated on-board RC oscillator is used for a POR timer function. The POR time allows V_{CC} and the oscillator circuit to stabilize before instruction execution begins. The POR timer circuit is a one-shot timer triggered by one of the four following conditions:

- Power bad to power good status
- Stop-Mode Recovery
- WDT time-out
- WDH time-out (in Halt Mode)
- WDT time-out (in Stop Mode)

Watch-Dog Timer Reset. The WDT is a retriggerable one-shot timer that resets the Z8 if it reaches its terminal count. The WDT is initially enabled by executing the WDT instruction and is retriggered on subsequent execution of the WDT instruction. The timer circuit is driven by an onboard RC oscillator. If the permanent WDT option is selected then the WDT is enabled after reset and operates in RUN Mode, HALT mode, STOP mode and cannot be disabled. If the permanent WDT option is not selected then the WDT, when enabled by the user's software, does not

operate in STOP Mode, but it can operate in HALT Mode by using a WDH instruction.

Table 4. Control Register

			R	Rese	et C	ond	litio	n		
Addr	Reg.	D7	D6	D5	D4	D3	D2	D1	D0	Comments
FF	SPL	0	0	0	0	0	0	0	0	
FE	GPR	0	0	0	0	0	0	0	0	
FD	RP	0	0	0	0	0	0	0	0	
FC	FLAGS	U	U	U	U	U	U	U	U	
FB	IMR	0	U	U	U	U	U	U	U	
FA	IRQ	U	U	0	0	0	0	0	0	IRQ3 is used for positive edge detection
F9	IPR	U	U	U	U	U	U	U	U	
F8	P01M	U	U	U	0	U	U	0	1	
F7*	P3M	U	U	U	U	U	U	0	0	P2 open-drain
F6*	P2M	1	1	1	1	1	1	1	1	Inputs after reset
F3	PRE1	U	U	U	U	U	U	0	0	
F2	T1	U	U	U	U	U	U	U	U	
F1	TMR	0	0	0	0	0	0	0	0	

Note:

*Registers are not reset after a STOP-Mode Recovery using P27 pin. A subsequent reset will cause these control registers to be reconfigured as shown in Table 4 and the user must avoid bus contention on the port pins or it may affect device reliability.



Program Memory. The Z8 addresses up to 512 bytes of internal program memory (Figure 12). The first 12 bytes of program memory are reserved for the interrupt vectors. These locations contain six 16-bit vectors that correspond to the six available interrupts. Bytes 0-511 are on-chip one-time programmable ROM.

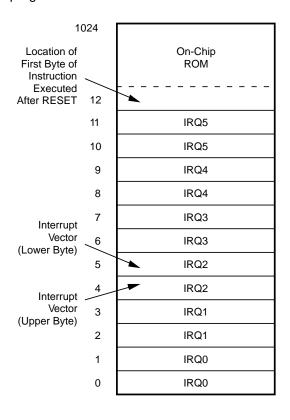


Figure 12. Program Memory Map

Register File. The Register File consists of three I/O port registers, 61 general-purpose registers, and 12 control and status registers R0-R3, R4-R127 and R241-R255, respectively (Figure 13). General-purpose registers occupy the 04H to 7FH address space. I/O ports are mapped as per the existing CMOS Z8. The instructions can access registers directly or indirectly through an 8-bit address field. This allows short 4-bit register addressing using the Register Pointer. In the 4-bit mode, the register file is divided into eight working register groups, each occupying 16 continuous locations. The Register Pointer (Figure 14) addresses the starting location of the active working-register group.

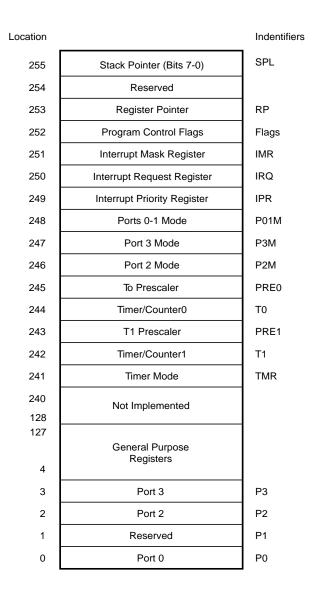


Figure 13. Register File

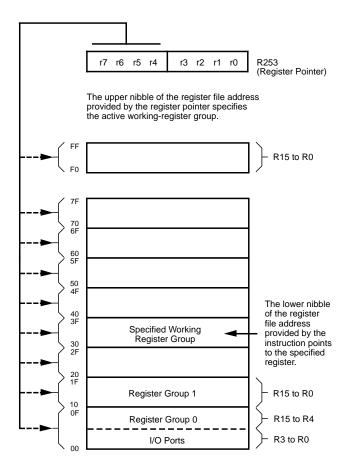


Figure 14. Register Pointer

Stack Pointer. The Z8 has an 8-bit Stack Pointer (R255) used for the internal stack that resides within the 60 general-purpose registers. It is set to 00Hex after any reset.

General-Purpose Registers (GPR). These registers are undefined after the device is powered up. The registers keep their last value after any reset, as long as the reset occurs in the V_{CC} voltage-specified operating range. **Note:** Register R254 has been designated as a general-purpose register. But is set to 00Hex after any reset.

Counter/Timer. There is an 8-bit programmable counter/timers (T1), each driven by its 6-bit programmable prescaler. The T1 prescaler is driven by internal or external clock sources. (Figure 15).

The 6-bit prescaler divide the input frequency of the clock source by any integer number from 1 to 64. The prescaler

drives its counter, which decrements the value (1 to 256) that has been loaded into the counter. When both counter and prescaler reach the end of count, a timer interrupt request IRQ5 (T1) is generated.

The counter can be programmed to start, stop, restart to continue, or restart from the initial value. The counters are also programmed to stop upon reaching zero (Single-Pass mode) or to automatically reload the initial value and continue counting (Modulo-N Continuous Mode).

The counter, but not the prescaler, is read at any time without disturbing its value or count mode. The clock source for T1 is user-definable and is either the internal microprocessor clock divided by four, or an external signal input through Port 3. The Timer Mode register configures the external timer input (P31) as an external clock, a trigger input that is retriggerable or non-retriggerable, or used as a gate input for the internal clock.



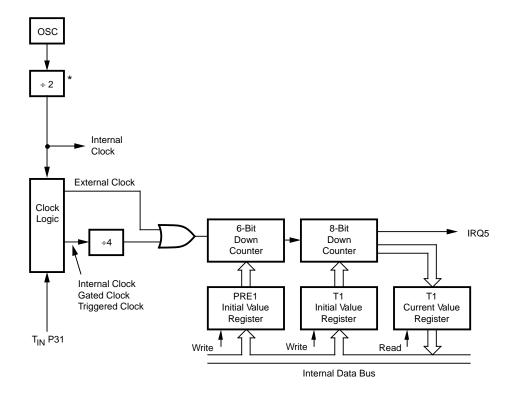


Figure 15. Counter/Timers Block Diagram

Interrupts. The Z8 has five interrupts from four different sources. These interrupts are maskable and prioritized (Figure 16). The sources are divided as follows: the falling edge of P31 (AN1), P32 (AN2), P33 (REF), the rising edge of P32 (AN2), and one counter/timer. The Interrupt Mask Register globally or individually enables or disables the five interrupt requests (Table 5).

When more than one interrupt is pending, priorities are resolved by a programmable priority encoder that is controlled by the Interrupt Priority register. All Z8 interrupts are vectored through locations in program memory. When an Interrupt machine cycle is activated, an Interrupt Request is granted. This disables all subsequent interrupts, saves the Program Counter and Status Flags, and then branches to the program memory vector location reserved for that interrupt. This memory location and the next byte contain the 16-bit starting address of the interrupt service routine for that particular interrupt request.

To accommodate polled interrupt systems, interrupt inputs are masked and the interrupt request register is polled to determine which of the interrupt requests needs service.

User must select any Z86E08 mode in Zilog's C12 ICE-BOX $^{\text{TM}}$ emulator. The rising edge interrupt is not directly supported on the Z86CCP00ZEM emulator.

Table 5. Interrupt Types, Sources, and Vectors

Name	Source	Vector Location	Comments
IRQ0	AN2(P32)	0,1	External (F)Edge
IRQ1	REF(P33)	2,3	External (F)Edge
IRQ2	AN1(P31)	4,5	External (F)Edge
IRQ3	AN2(P32)	6,7	External (R)Edge
IRQ4	Reserved	8,9	Reserved
IRQ5	T1	10,11	Internal
Notes:			
F = Fallir	ng edge triggered	k	
R = Risir	ng edge triggered	k	

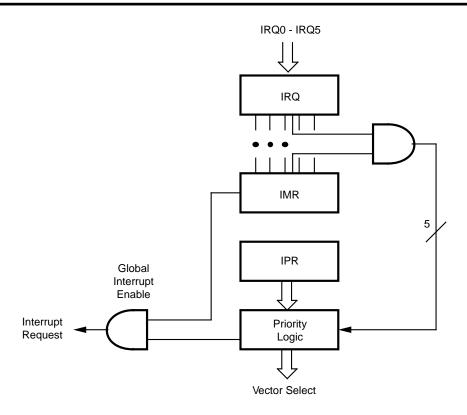


Figure 16. Interrupt Block Diagram

Clock. The Z8 on-chip oscillator has a high-gain, parallel-resonant amplifier for connection to a crystal, ceramic resonator, or any suitable external clock source (XTAL1 = IN-PUT, XTAL2 = OUTPUT). The crystal should be AT cut, 8 MHz max, with a series resistance (RS) of less than or equal to 100 Ohms.

The crystal or ceramic resonator should be connected across XTAL1 and XTAL2 using the vendors crystal or ceramic resonator recommended capacitors from each pin directly to device ground pin 14 (Figure 17). Note that the crystal capacitor loads should be connected to V_{SS} , Pin 14 to reduce Ground noise injection.

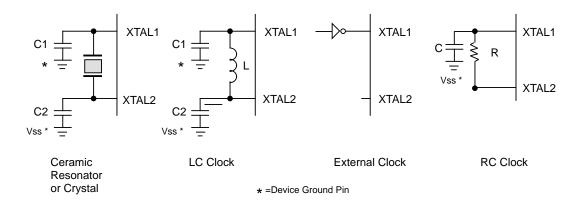


Figure 17. Oscillator Configuration



HALT Mode. This instruction turns off the internal CPU clock but not the crystal oscillation. The counter/timer and external interrupts IRQ0, IRQ1, IRQ2 and IRQ3 remain active. The device is recovered by interrupts, either externally or internally generated. An interrupt request must be executed (enabled) to exit HALT mode. After the interrupt service routine, the program continues from the instruction after the HALT.

STOP Mode. This instruction turns off the internal clock and external crystal oscillation and reduces the standby current to 10 μ A. The STOP mode is released by a RESET through a Stop-Mode Recovery (pin P27). A Low input condition on P27 releases the STOP mode. Program execution begins at location 000C(Hex). However, when P27 is used to release the STOP mode, the I/O port mode registers are not reconfigured to their default power-on conditions. This prevents any I/O, configured as output when the STOP instruction was executed, from glitching to an unknown state. To use the P27 release approach with STOP mode, use the following instruction:

LD P2M, #1XXX XXXXB NOP STOP

Notes:

X = Dependent on user's application.Stop-Mode Recovery pin P27 is not edge triggered.

In order to enter STOP or HALT mode, it is necessary to first flush the instruction pipeline to avoid suspending execution in mid-instruction. To do this, the user executes a NOP (opcode=FFH) immediately before the appropriate SLEEP instruction, i.e.:

FF NOP ; clear the pipeline 6F STOP ; enter STOP mode

or

FF NOP ; clear the pipeline 7F HALT ; enter HALT mode

Watch-Dog Timer (WDT). The Watch-Dog Timer is enabled by instruction WDT. When the WDT is enabled, it cannot be stopped by the instruction. With the WDT instruction, the WDT is refreshed when it is enabled within every 1 Twdt period; otherwise, the controller resets itself, The WDT instruction affects the flags accordingly; Z=1, S=0, V=0. WDT = 5F (Hex)

Opcode WDT (5FH). The first time opcode 5FH is executed, the WDT is enabled and subsequent execution clears the WDT counter. This must be done at least every T_{WDT} ; otherwise, the WDT times out and generates a reset. The generated reset is the same as a power-on reset of T_{POR} , plus 18 XTAL clock cycles. The WDT does not run in stop mode, unless the permanent WDT enable option is selected. The WDT does not run in halt mode unless WDH instruction is executed or permanent WDT enable option is selected.

Opcode WDH (4FH). When this instruction is executed it enables the WDT during HALT. If not, the WDT stops when entering HALT. This instruction does not clear the counters, it just makes it possible to have the WDT running during HALT mode. A WDH instruction executed without executing WDT (5FH) has no effect.

Note: Opcode WDH and permanently enabled WDT is not directly supported by the Z86CCP00ZEM.

Auto Reset Voltage (V_{LV}). The Z8 has an auto-reset builtin. The auto-reset circuit resets the Z8 when it detects the V_{CC} below V_{LV} . Figure 18 shows the Auto Reset Voltage versus temperature.

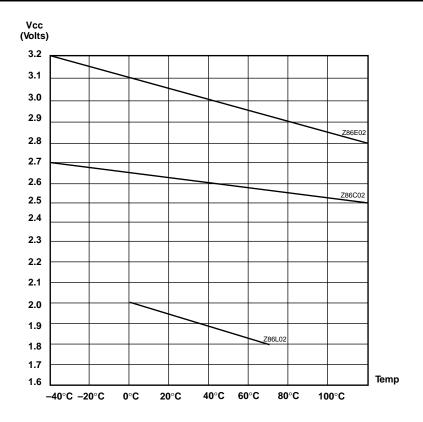


Figure 18. Typical Auto Reset Voltage (V_{LV}) vs. Temperature

Options

The Z86C02/E02/L02 offers ROM protect, Low Noise, Auto Latch Disable, RC Oscillator, and Permanent WDT enable features as options. The Z86E02 must be power cycled to fully implement the selected option after programming.

Low Noise. The Z8 can operate in a low EMI emission mode by selecting the low noise option. Use of this feature will result in:

- All drivers slew rates are reduced to 10 ns (typical).
- Internal SCLK/TCLK = XTAL operation is limited to a maximum of 4 MHz - 250 ns cycle time.
- Output drivers have resistances of 200 ohms (typical).
- Oscillator divide-by-two circuitry is eliminated.

ROM Protect. ROM Protect fully protects the Z8 ROM code from being read externally. When ROM Protect is selected, the instructions LDC and LDCI are supported. (However, instructions LDE and LDEI are not supported.)

EPROM/TEST MODE Disable. When selected, this bit will permanently disable EPROM and Factory Test mode.

Auto Latch Disable. Auto Latch Disable option when Selected will globally disable all Auto Latches.

RC. RC Oscillator option when selected will allow using a resistor (R) and a capacitor (C) as a clock source.

WDT Enable. WDT Enable option bit when selected will have the WDT permanently enabled in all modes and can not be stopped in HALT or STOP Mode.

EPROM Mode Description. In addition to V_{DD} and GND (V_{SS}), the Z8 changes all its pin functions in the EPROM mode. XTAL2 has no function, XTAL1 functions as /CE, P31 functions as /OE, P32 functions as EPM, P33 functions as V_{PP}, and P02 functions as /PGM.

Please note that when using the device in a noisy environment, it is suggested that the voltages on the EPM and CE pins be clamped to V_{CC} through a diode to V_{CC} to prevent accidentally entering the OTP mode. The V_{PP} requires both a diode and a 100 pF capacitor.

User Modes. Table 6 shows the programming voltage of each mode of Z86E02.



Table 6. EPROM Programming Table

Programming								
Modes	V_{PP}	EPM	/CE	/OE	/PGM	ADDR	DATA	v _{cc} *
EPROM READ	NU	V _H	V _{IL}	V _{IL}	V _{IH}	ADDR	Out	5.0V
PROGRAM	V _H	V _{IH}	V_{IL}	V _{IH}	V _{IL}	ADDR	In	6.4V
PROGRAM VERIFY	V _H	V _{IH}	V _{IL}	V _{IL}	V _{IH}	ADDR	Out	6.4V
ROM PROTECT	V _H	V_{H}	V _H	V _{IH}	V _{IL}	NU	NU	5.0-6.4V
LOW NOISE SELECT	V _H	V _{IH}	V _H	V_{IH}	V_{IL}	NU	NU	5.0-6.4V
AUTO LATCH DISABLE	V _H	V_{IH}	V _H	V_{IL}	V_{IL}	NU	NU	5.0-6.4V
WDT ENABLE	V_{H}	V_{IL}	V_{H}	V_{IH}	V_{IL}	NU	NU	5.0-6.4V
EPROM/TEST MODE Disable	V_{H}	V_{IL}	V_{H}	V_{IL}	V_{IL}	NU	NU	5.0-6.4V

Notes: $V_H = 13.0 V \pm 0.25 V_{DC}$.

V_{IH}=As per specific Z8 DC specification.

V_{II} =As per specific Z8 DC specification.

X=Not used, but must be set to V_H , V_{IH} , or V_{IL} level.

NU=Not used, but must be set to either V_{IH} or V_{IL} level.

I_{PP} during programming = 40 mA maximum.

I_{CC} during programming, verify, or read = 40 mA maximum.

Internal Address Counter. The address of Z86E02 is generated internally with a counter clocked through pin P01 (Clock). Each clock signal increases the address by one and the "high" level of pin P00 (Clear) will reset the address to zero. Figure 19 shows the setup time of the serial address input.

Programming Waveform. Figures 20, 21, 22, and 23 show the programming waveforms of each mode. Table 7 shows the timing of programming waveforms.

Programming Algorithm. Figure 24 shows the flow chart of the Z86E02 programming algorithm.

Table 7. Z86E02 Timing of Programming Waveforms

Parameters	Name	Min	Max	Units
1	Address Setup Time	2		μs
2	Data Setup Time	2		μs
3	V _{PP} Setup	2		μs
4	V _{CC} Setup Time	2		μs
5	Chip Enable Setup Time	2		μs
6	Program Pulse Width	0.95		ms
7	Data Hold Time	2		μs
8	/OE Setup Time	2		μs
9	Data Access Time	188	4000	ns
10	Data Output Float Time		100	ns
11	Over-program Pulse Width	2.85	3.2	ms
12	EPM Setup Time	2		μs
13	/PGM Setup Time	2		μs
14	Address to /OE Setup Time	2		μs
15	Option Program Pulse Width	150		ms
16	/OE Low Width	250		ns

^{*} V_{CC} has a tolerance of ±0.25V.

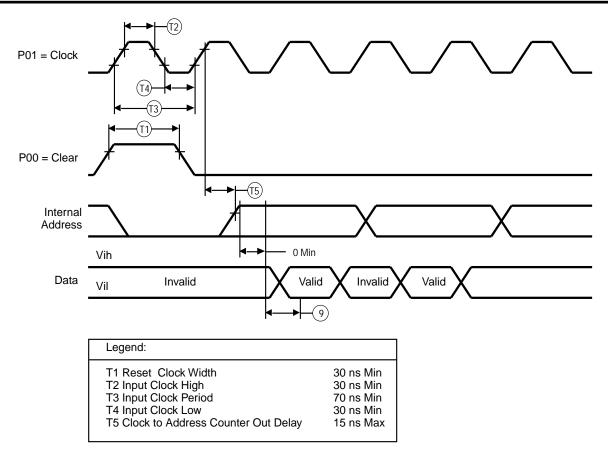


Figure 19. Z86E02 Address Counter Waveform



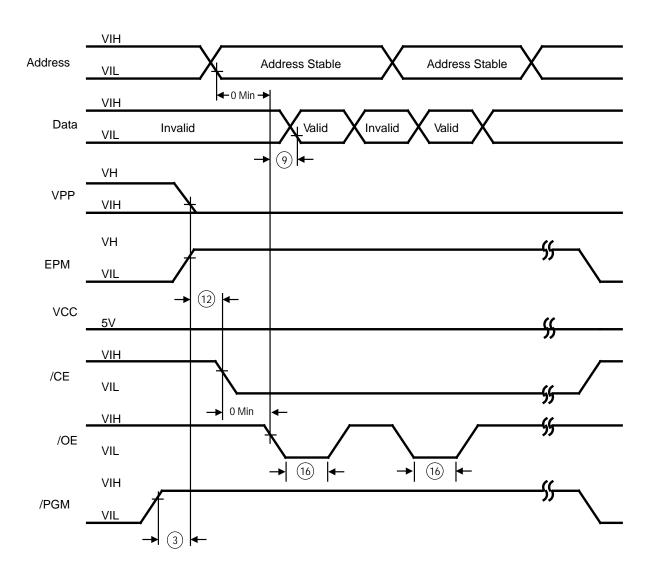


Figure 20. Z86E02 Programming Waveform (EPROM Read)

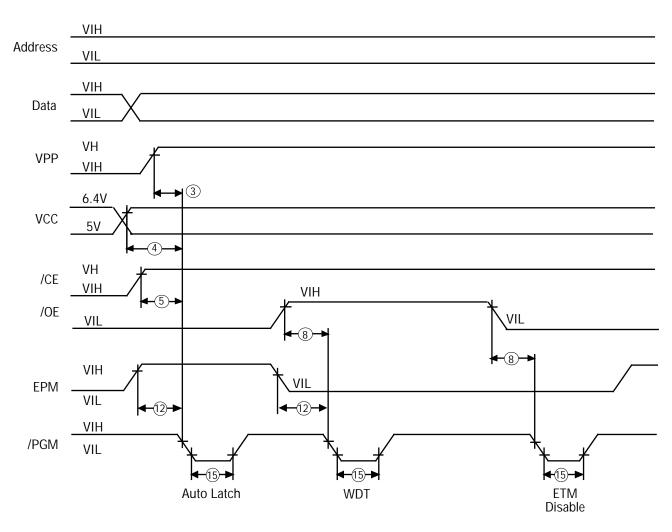


Figure 21. Z86E02 Programming Waveform (Program and Verify)

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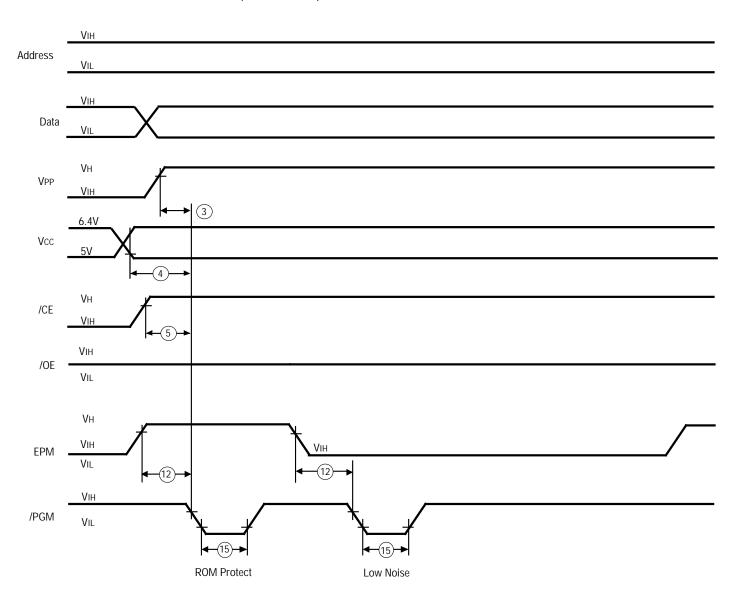


Figure 22. Z86E02 Programming Options Waveform (ROM Protect and Low Noise Program)

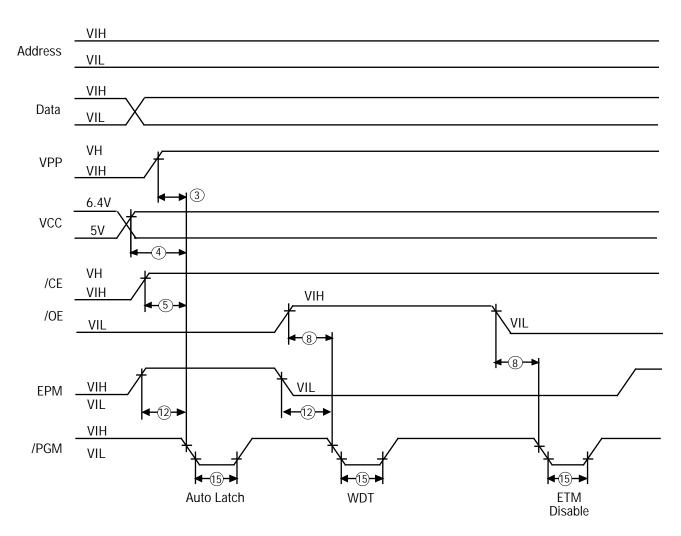


Figure 23. Z86E02 Programming Options Waveform (Auto Latch Disable, Permanent WDT Enable, and EPROM/TEST MODE Disable)

DS96DZ80301 (11/96) PRELIMINARY 1-31



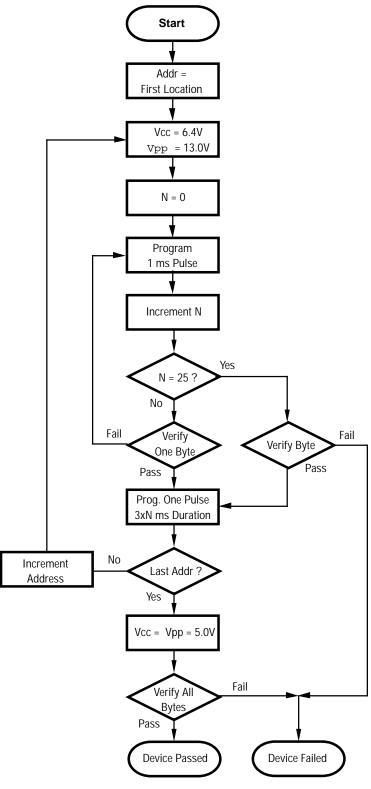


Figure 24. Z86E02 Programming Algorithm

Z8 CONTROL REGISTERS

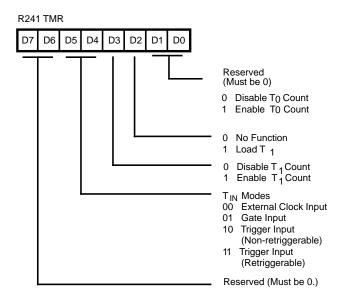


Figure 25. Timer Mode Register (F1_H: Read/Write)

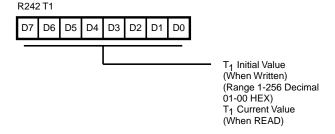


Figure 26. Counter Timer 1 Register (f2_H:Read/Write)

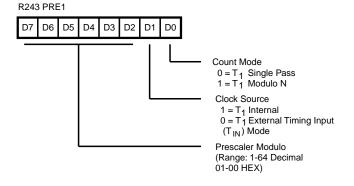


Figure 27. Prescaler! Register (F3_H: Write Only)

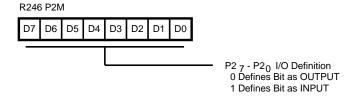


Figure 28. Port 2 Mode Register (F6_H: Write Only)

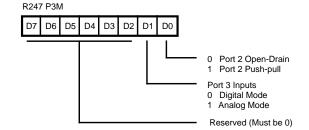


Figure 29. Port 3 Mode Register (F7_H: Write Only)

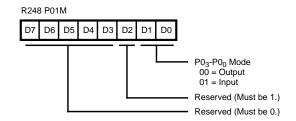


Figure 30. Port 0 and 1 Mode Register (F8_H: Write Only)

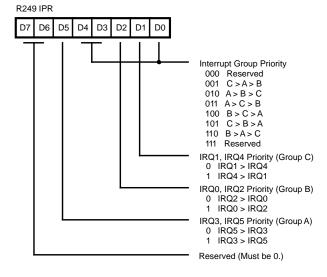


Figure 31. Interrupt Priority Register (F9_H: Write Only)



Z8 CONTROL REGISTERS (Continued)

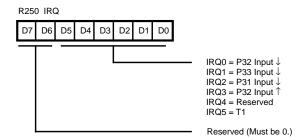


Figure 32. Interrupt Request Register (FA_H: Read/Write)

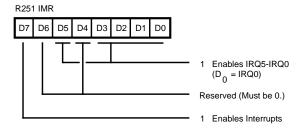


Figure 33. Interrupt Mask Register (FB_H: Read/Write)

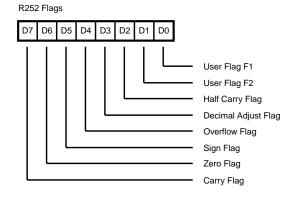


Figure 34. Flag Register (FC_H: Read/Write)

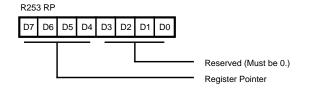


Figure 35. Register Pointer FD_H: Read/Write)

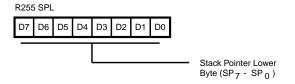
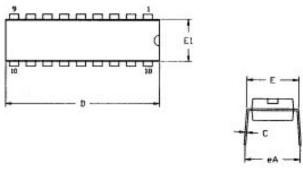
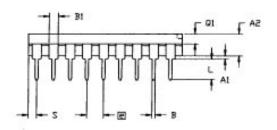


Figure 36. Stack Pointer (FF_H: Read/Write)

PACKAGE INFORMATION







SYMBOL	MILLI	METER	IN	CH
J. HOLL	MIN	MAX	MIN	MAX
AL	0.51	18.0	050.	.032
A2	3.25	3.43	.128	135
В	0.38	0.53	.015	.021
B1	1.14	1.65	.045	.065
C	0.23	0.38	.009	.015
D	22.35	23.37	.880	.920
E	7.62	8.13	.300	.320
E1	55.6	6.48	.245	.255
E	2.54	TYP	.100	TYP
eA	7.87	8.89	.310	.350
L	3.18	3.01	125	.150
Q1	1.52	1.65	.060	.065
2	0.89	1.65	.035	.065

CONTROLLING DIMENSIONS + INCH.

Figure 37. 18-Pin DIP Package Diagram

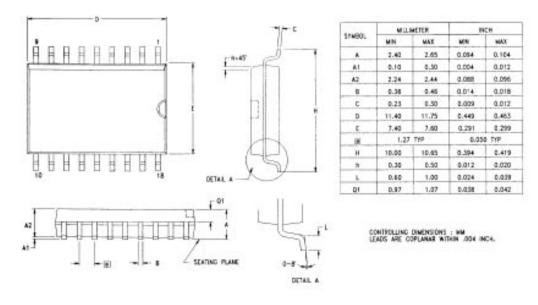


Figure 38. 18-Pin SOIC Package Diagram



ORDERING INFORMATION

Standard Temperature

18-Pin DIP18-Pin SOICZ86E0208PSCZ86E0208SSCZ86L0208PSCZ86L0208SSCZ86C0208PSCZ86C0208SSCZ86E0208PSC1903Z86E0208SSC1903

Extended Temperature

18-Pin DIP18-Pin SOICZ86E0208PECZ86E0208SECZ86L0208PECZ86L0208SECZ86C0208PECZ86C0208SECZ86E0208PEC1903Z86E0208SEC1903

For fast results, contact your local Zilog sales office for assistance in ordering the part(s) desired.

CODES

Preferred Package Speed
P = Plastic DIP 08 = 8 MHz

Longer Lead Time

Environmental

S = SOIC

C = Plastic Standard

Preferred Temperature

 $S = 0^{\circ}C$ to $+70^{\circ}C$

 $E = -40^{\circ}C \text{ to } +105^{\circ}C$

Example:

